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Superconductivity above 30 K Achieved in Dense Scandium

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Superconductivity is one of most intriguing quantum phenomena, and the quest for elemental superconductors with high critical temperature (T_c) is of great scientific significance due to their relatively simple material composition and the underlying mechanism. Here we report the experimental discovery of densely compressed scandium (Sc) becoming the first elemental superconductor with T_c breaking into 30 K range, which is comparable to the T_c values of the classic La–Ba–Cu–O or LaFeAsO superconductors. Our results show that T_c^{onset} of Sc increases from ∼3 K at around 43 GPa to ∼32 K at about 283 GPa (T_c^{zero} ∼ 31 K), which is well above liquid neon temperature. Interestingly, measured T_c shows no sign of saturation up to the maximum pressure achieved in our experiments, indicating that T_c may be even higher upon further compression.

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Searching for high T_c superconductors is one of most important research topics in physical sciences. Elemental superconductors attract special and growing attention due to the simplicity of their singular composition.[1,2] About 20 elemental solids are known to show superconductivity at ambient pressure, of which niobium has the highest superconducting transition temperature T_c ∼ 9.2 K[1] and its alloy NbTi has been widely used for its excellent superconducting performance.[3] High pressure is a powerful tool and has been playing an important role in exploring new elemental superconductors and tuning superconducting properties.[2] For simple elemental metals, high pressure usually suppresses T_c because of the electronic band broadening and resulting reduction of the density of states near the Fermi energy. Lattice stiffness is another important factor that T_c goes down under pressure. However, these pressure effects on superconductivity may be altered by subtle structural and electronic changes associated with bonding or phase transitions. Pressure may also enable non-superconducting metals or even insulating solids at ambient pressure to host superconductivity at high pressure. For example, calcium is non-superconducting at ambient pressure, but exhibits a high T_c of 25 K at 161 GPa,[4] and insulating sulfur shows superconductivity with T_c ∼ 17 K at 200 GPa.[5] All known elemental superconductors with T_c near or above 20 K are realized under pressure, such as Li with T_c ∼ 16–20 K at 43–48 GPa[6,7] and yttrium with T_c ∼ 17 K at 89 GPa.[8] Our recent study showed that elemental titanium can reach T_c of 26.2 K at pressure of 248 GPa.[9]

It is indicated that both Ca and Ti show very high T_c among elemental solids because of the pressure induced *s*–*d* electron transition, which also drives a sequence of phase transitions.[4,9–14] The structure instability associated with the pressure induced tendency and occurrence of phase transitions favors superconductivity because of the lattice softening enhanced electron-phonon coupling strength.[9] The crystal structure and physical properties of Sc metal under pressure were examined in previous studies,[15–24] which showed that Sc has the *hcp* structure (Sc I) under ambient conditions, and pressure generates four structural transitions at about 23, 104, 140, and 240 GPa, respectively, producing high-pressure phases of Sc Ⅱ, Sc Ⅲ, Sc Ⅳ, and Sc V, respectively.[17–19] Sc Ⅱ phase crystallizes in an incommensurate composite structure comprising a body centered host structure and a *C* face centered guest structure,[18] and Sc V phase has a hexagonal lattice consisting of six screw helical chains,[17] while Sc Ⅲ and Sc Ⅳ phases are not fully determined.[19]

Previous work reported that Sc starts to show superconductivity at 21 GPa with T_c ∼ 0.35 K.[21] With further compression, T_c reaches as high as 19.6 K at 107 GPa, which occurs just at the phase boundary of Sc Ⅱ and Sc Ⅲ. However, T_c was reported to drop to ∼10 K when pressure

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is further increased and Sc Ⅲ phase appears.[20] Here, we report high-pressure measurements up to 283 GPa to explore superconductivity in Sc. A maximal T_c above 30 K was observed at the highest experimental pressure, which sets a new record among elemental superconductors. To date, Sc is the only known elemental superconductor with T_c breaking into 30 K temperature range.

Experimental. The electrical resistance measurements were performed by using the four probe van der Pauw method for tiny specimen as described in the literature.[25,26] The pressure was calibrated via the shift of the first order Raman edge frequency from the diamond cutlet as shown in the previous reports.[9,27,28] The applied current is 100 μA. Diamond anvil cells were used to produce high pressures. A variant of anvils with double beveled culet size of 20/140/300 μm, 30/140/300 μm, or 50/140/300 μm were adopted in the experiments. A plate of T301 stainless steel covered with mixture of c-BN powder and epoxy as insulating layer was used as the gasket. A hole of approximately 15 ∼ 30 μm in diameter depending on top culet size was drilled in the center of the gasket to serve as high pressure chamber. Also, h-BN powder was used as pressure transmitting medium that filled the high pressure chamber. We used the ATHENA procedure to produce the specimen assembly.[26] Four Pt foils with thickness of approximately 0.5 μm as the inner electrode were deposited on the culet surface, after which cross shaped Sc specimens with side lengths ∼10 μm ×10 μm and thickness of 1 μm were adhered on the electrodes and culet surface. Tens of specimens are prepared for the experiments. Diamond anvil cells were put into a MagLab system that provides synergetic extreme environments with temperatures from 300 to 1.5 K and magnetic fields up to 9 T for the transport measurements.

Results and Discussion. Figure 1(a) shows the temperature dependence of electrical resistance at high pressure up to 215 GPa measured during the warming process for Sc sample 1. The Sc metal starts to show superconductivity with T_c above 3.3 K at 43 GPa. The T_c monotonously rises to ∼26.2 K at 215 GPa, which is much higher than the 8.2 K at 74 GPa reported by Hamlin *et al.*[22] and 19.6 K at 107 GPa reported by Debessai *et al.*[20] Considering that T_c shows an increasing tendency with further compression, we extended to higher pressures up to 283 GPa for sample 2 and observed enhancement of T_c in dense Sc metal. Temperature dependence of the electrical resistance for sample 2 under various pressures are shown in Fig. 1(b). With further increasing pressure, T_c reaches 32 K at the maximum experimental pressure of 283 GPa as shown in Fig. 2, where both cooling and warming curves are presented. It is evidenced in the experiments that cooling process usually gave rather higher transition temperature since it is not easy to reach thermal equilibrium with helium cooling rate. Alternatively the warming process can be subtly tuned to reach thermal equilibrium that approaches the intrinsic properties of the measured samples. We hence chose the T_c measured from warming process. For the warming process the onset critical temperature (T_c^{onset}) and the zero resistance critical temperature (T_c^{zero}) of superconducting transition at 283 GPa can be determined by the derivative of resistance with respect to temperature, i.e., dR/dT, to be 32 K and 31 K, respectively, demonstrating a very narrow superconducting transition. The data for samples 3 and 4 shown by Figs. S1(a) and S1(b) in the Supplementary Materials further confirm the superconductivity of Sc under high pressure with T_c above 30 K.

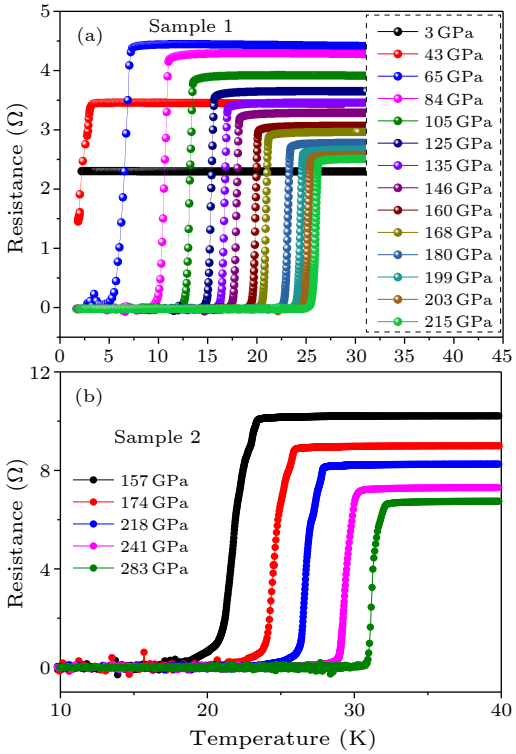

Fig. 1. Temperature dependence of the electrical resistance of elemental Sc metal measured at high pressures for (a) sample 1 and (b) sample 2.

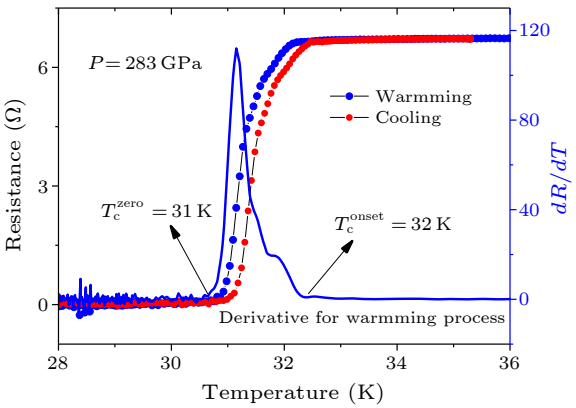

Fig. 2. The resistance curves measured at 283 GPa in both cooling and warming processes, where the derivative of the resistance with respect to temperature, dR/dT, for the warming process is plotted to clearly show the T_c^{onset} and T_c^{zero}.

Among elemental superconductors, niobium has the highest T_c of 9.2 K at ambient pressure, while under high pressure several elements exhibit high T_c near or above 20 K, such as Li (T_c ∼ 15–20 K at 48 GPa[6,7]), Ca (T_c ∼ 25 K at 220 GPa[4]), Y (T_c ∼ 20 K near 100 GPa[8]), V (T_c ∼ 17 K at 120 GPa[29]), S (T_c ∼ 17 K at 220 GPa[5]),

and Ti ($T_c \sim 26.2$ K near 248 GPa[9]). Superconductivity above 30 K in elemental solids has never been reported before, and Sc is the first and so far only known elemental superconductor with T_c breaking into the record-setting 30 K range, which is comparable to the T_c of the classic LaBaCuO[30] and LaFeAsO superconductors.[31]

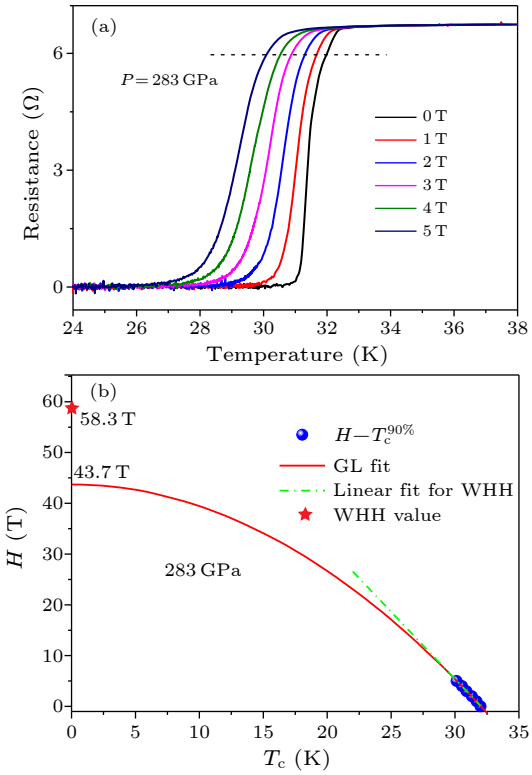

Fig. 3. (a) Temperature dependence of the electrical resistance of Sc metal measured at different magnetic fields under fixed pressure of 283 GPa. The dashed line marks the 90% of the normal state resistance. (b) Upper critical field $\mu_0 H_{c2}$ versus temperature at 283 GPa. The Ginzburg–Landau (GL) fit for the H_{c2} (T) is shown by the solid lines. The star symbol represents the H_{c2} (0) values calculated via the Werthamer–Helfand–Hohenberg (WHH) model.

To further probe superconductivity of dense Sc metal under high pressure, we measured transport properties under different magnetic fields for sample 2. Figure 3(a) presents the electrical resistance measured at 283 GPa with applying magnetic fields. It is seen that the superconducting transitions are gradually suppressed by the magnetic field. Here, the temperature at 90% of normal state resistance was used to plot the data of $T_c^{90\%}$ versus magnetic field measured at 283 GPa as shown in Fig. 3(b), from which the upper critical field at zero temperature $\mu_0 H_{c2}(0)$ can be estimated. A linear fitting of $H_{c2}(T)$ leads to the slope of $dH_{c2}/dT|_{T_c}$ of -2.65 T/K. Using the Werthamer–Helfand–Hohenberg (WHH) formula of $\mu_0 H_{c2}(T) = -0.69 \times [dH_{c2}/dT|_{T_c}] \times T_c$, the $\mu_0 H_{c2}(0)$ value controlled by orbital depairing mechanism in a dirty limit $[\mu_0 H_{c2}^{orb}(0)]$ was calculated to be 58 T. The Ginzburg–Landau (GL) formula of $\mu_0 H_{c2}(T) = \mu_0 H_{c2}(0) \times [1 - (T/T_c)^2]$ is also used to estimate the upper critical field at zero temperature. As shown in Fig. 3(b), the fitting of $\mu_0 H_{c2}(T)$ by the GL formula gives a value of $H_{c2}(0) = 43.7$ T, which is slightly smaller than $\mu_0 H_{c2}^{orb}(0)$. Using the obtained value of $H_{c2}(0)$, the GL coherence length was calculated to be $\xi = 27.4$ Å via $\mu_0 H_{c2}(0) = \Phi_0/2\pi\xi^2$, where $\Phi_0 = 2.067 \times 10^{-15}$ Web is the magnetic flux quantum.

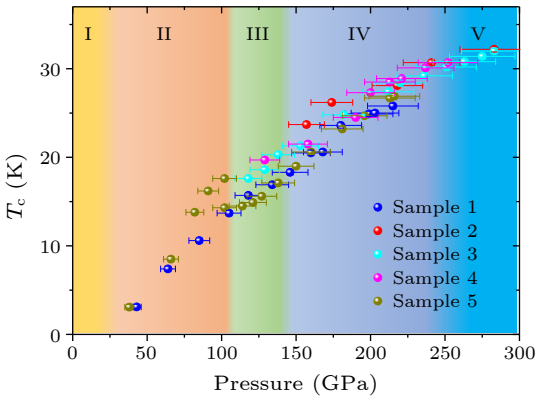

Fig. 4. Phase diagram of superconducting transition temperature T_c and crystal structure versus pressure for Sc. The measured results on all the five samples show consistent trends.

Combining our high-pressure x-ray experiments (Fig. S2) and the phase transition behaviors reported previously,[17–19] we plot the pressure-driven structure-superconductivity phase diagram as shown in Fig. 4. Five different crystal structures of Sc are identified when pressure varies from ambient pressure to 297 GPa. No superconductivity above 2 K was observed in Sc I within the pressure range 0–23 GPa. With increasing pressure, T_c monotonously rises from 3.1 K at 43 GPa to 32 K at 283 GPa as shown by the data of thin foil samples 1–4. One remarkable interesting feature is the pressure dependence of T_c, showing non-saturating behavior, which suggests that T_c could be further enhanced by further compression under higher-pressure conditions. We note that the monotonous rise of T_c is different from the previous work reported by Debessai *et al.*,[20] where an abrupt T_c drop is found at 111 GPa that is near the boundary between the Sc Ⅱ and Sc Ⅲ phases. To double check this discrepancy, one additional high-pressure transport measurement was performed on powder Sc sample instead of thin film. As shown in Figs. S1(c) and S1(d), at 102 GPa there exist two superconducting transitions at 17.5 K and 14 K, respectively. With further increasing pressure, the low-T_c transition gradually shifts toward high temperature while the high T_c transition disappears, which implies that there does exist a phase transition near 102 GPa. The low-T_c superconductivity should arise from the Sc Ⅲ phase, which is consistent with the T_c drop near the phase transition reported in the previous work.[20] Except for the data in the Sc Ⅱ phase in the range 82–102 GPa, the pressure dependences of T_c for the thin film and powder samples are well matched. Sc Ⅱ phase adopts an incommensurate modulated host-guest structure with space group $I4/mcm$ (γ).[18] This incommensurate structure consists of two interpenetrating sublattices, a body-centered host structure and a C face centered guest structure, along the crystallographic c axis. For powder Sc sample, the incom-

mensurability increases with pressure [18] and T_c increases accordingly. [20] It is speculated that the strain in the thin film samples should suppress the increase of incommensurability under high pressure relative to the powder sample and lead to the T_c discrepancy. In the phases from Sc Ⅲ to Sc V, T_c rises consistently at rising pressure. Sc Ⅲ and Sc Ⅳ phases are not fully resolved, although a recent theoretical study suggested that the *Ccca*20 phase and *Cmca*32 phase are likely candidates for the observed Sc Ⅲ and Sc Ⅳ, respectively. [19] Sc V phase occurs when pressure exceeds 240 GPa, which adopts a hexagonal lattice (space group $P6_122$) consisting of six screw helical chains. [17] These results suggest that pressure-induced structure instability plays a key role in driving rising T_c in dense Sc, possibly driven by rising contribution of d orbital electronic states near the Fermi energy and the lattice softening associated with the phase transitions, both of which strengthen the electron phonon coupling.

We also have performed electron phonon coupling density functional calculations to confirm the experimentally observed superconductivity as seen in Fig. S3. Details of the calculations are given in the Supplementary Materials. The predicted T_c at 240 GPa varies from 30 K to 33 K with empirical Coulomb repulsion parameter from 0.13 to 0.1. The results are similar to those reported in Ref. [32]. A valence electronic configuration Sc of $3s^{1.56}3p^{5.25}3d^{2.42}4s^{0.25}$ was obtained from the Mulliken population analysis of the crystal orbitals calculated using an atom-centered localized basis set. [33] It is obvious that the substantial charge migration from the Sc $4s$ to the $3d$ orbital is responsible for the strong electron phonon coupling.

In summary, we have investigated transport properties of Sc under high pressure up to 283 GPa, and found that T_c is monotonously enhanced by pressure from 3.1 K at around 43 GPa to 32 K at around 283 GPa, following a sequence of high-pressure phase transitions from Sc Ⅱ to Sc V. The increase of T_c shows no sign of saturation up to the highest experimental pressure of 283 GPa, which indicates that T_c of superconducting Sc still has room to go higher upon further compression. Scandium is the only currently known elemental superconductors with the $T_c^{\rm onset}$ breaking through 30 K at high pressure. The present results offer fresh insights for exploring high-T_c superconductivity at ultrahigh pressures in diverse element solids.

During preparing the paper (arXiv:2303.01062) we became aware that an independent similar work (arXiv:2302.14378) has been carried out by J. J. Ying *et al.* [32]

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